

Octal 3-STATE Transceiver

MM74HC245A

General Description

The MM74HC245A 3-STATE bidirectional buffer utilizes advanced silicon-gate CMOS technology, and is intended for two-way asynchronous communication between data buses. It has high drive current outputs which enable high speed operation even when driving large bus capacitances. This circuit possesses the low power consumption and high noise immunity usually associated with CMOS circuitry, yet has speeds comparable to low power Schottky TTL circuits.

This device has an active LOW enable input G and a direction control input, DIR. When DIR is HIGH, data flows from the A inputs to the B outputs. When DIR is LOW, data flows from the B inputs to the A outputs. The MM74HC245A transfers true data from one bus to the other.

This device can drive up to 15 LS-TTL Loads, and does not have Schmitt trigger inputs. All inputs are protected from damage due to static discharge by diodes to VCC and ground.

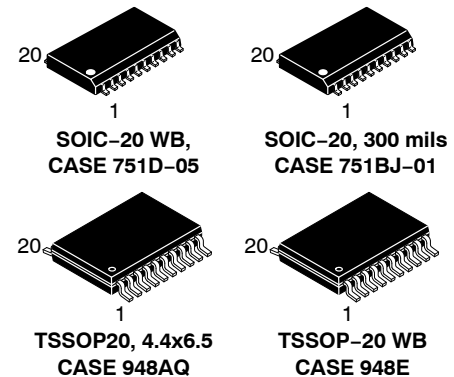
Features

- Typical Propagation Delay: 13 ns
- Wide Power Supply Range: 2 V to 6 V
- Low Quiescent Current: 160 μ A Maximum (74HC)
- 3-STATE Outputs for Connection to Bus Oriented Systems
- High Output Current: 6 mA (Minimum)
- Same as the 645
- These are Pb-Free Devices

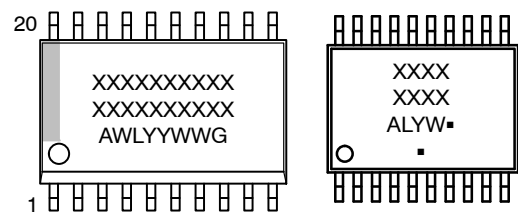
TRUTH TABLE

Control Inputs		Operation
$\bar{G}$	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

NOTE: H = HIGH Level
L = LOW Level
X = Irrelevant



MARKING DIAGRAM

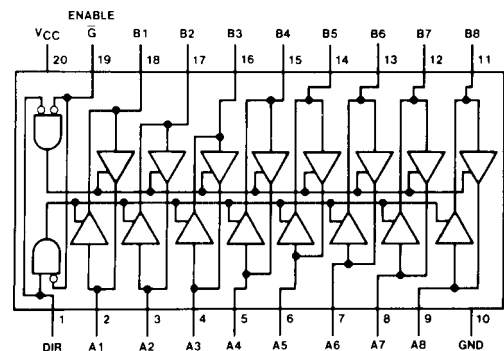


XXXXX = Specific Device Code
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G, ■ = Pb-Free Package

(Note: Microdot may be in either location)

CONNECTION DIAGRAM

Pin Assignment for SOIC and TSSOP



(Top View)

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

MM74HC245A

Logic Diagram

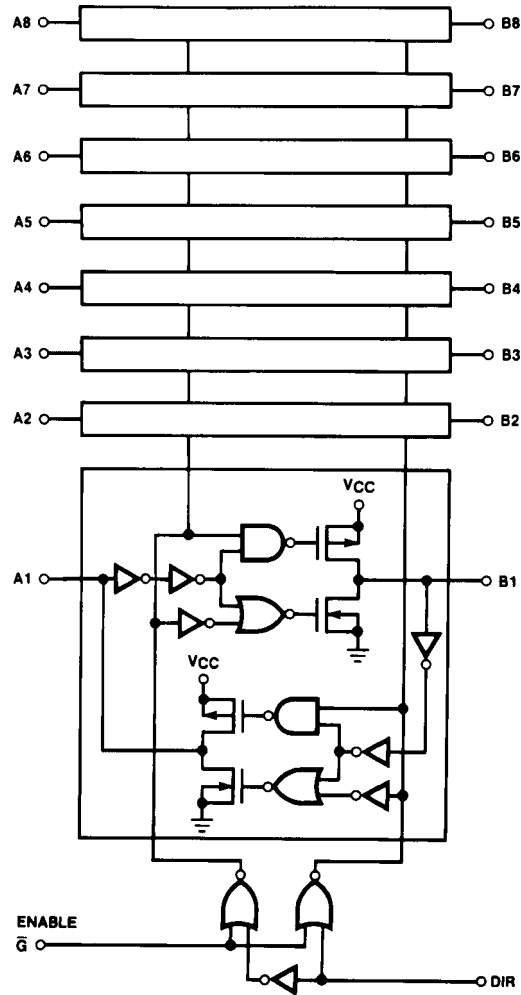


Figure 1. Logic Diagram

ABSOLUTE MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Rating	Unit
V_{CC}	Supply Voltage	-0.5 to +6.5	V
V_{IN}	DC Input Voltage DIR and $\overline{G}$ pins	-0.5 to $V_{CC} + 0.5$	V
V_{IN}, V_{OUT}	DC Input/Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{CD}	Clamp Diode Current	± 20	mA
I_{OUT}	DC Output Current, per pin	± 35	mA
I_{CC}	DC V_{CC} or GND Current, per pin	± 70	mA
T_{STG}	Storage Temperature Range	-65 to +150	°C
P_D	Power Dissipation	SOIC TSSOP 1302 833	mW
T_L	Lead Temperature (Soldering 10 seconds)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Unless otherwise specified all voltages are referenced to ground.

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RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	Supply Voltage	2	6	V
V_{IN}, V_{OUT}	DC Input or Output Voltage	0	V_{CC}	V
T_A	Operating Temperature Range	-55	+125	°C
t_r, t_f	Input Rise/Fall Times	$V_{CC} = 2.0\text{ V}$	1000	ns
		$V_{CC} = 4.5\text{ V}$	500	
		$V_{CC} = 6.0\text{ V}$	400	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (Note 2)

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C		T _A = −40°C to 85°C	T _A = −55°C to 125°C	Unit
				Typ.	Guaranteed Limits			
V _{IH}	Minimum HIGH Level Input Voltage		2.0	–	1.50	1.50	1.50	V
			4.5	–	3.15	3.15	3.15	
			6.0	–	4.20	4.20	4.20	
V _{IL}	Maximum LOW Level Input Voltage		2.0	–	0.50	0.50	0.50	V
			4.5	–	1.35	1.35	1.35	
			6.0	–	1.80	1.80	1.80	
V _{OH}	Minimum HIGH Level Output Voltage	V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 20 μA	2.0	2.0	1.9	1.9	1.9	V
			4.5	4.5	4.4	4.4	4.4	
			6.0	6.0	5.9	5.9	5.9	
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 6.0 mA	4.5	4.20	3.98	3.84	3.70	
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 7.8 mA	6.0	5.70	5.48	5.34	5.20	
V _{OL}	Maximum LOW Level Output Voltage	V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 20 μA	2.0	0	0.1	0.1	0.1	V
			4.5	0	0.1	0.1	0.1	
			6.0	0	0.1	0.1	0.1	
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 6.0 mA	4.5	0.20	0.26	0.33	0.40	
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 7.8 mA	6.0	0.20	0.26	0.33	0.40	
I _{IN}	Input Leakage Current (G and DIR)	V _{IN} = V _{CC} or GND	6.0	–	±0.1	±1.0	±1.0	μA
I _{OZ}	Maximum 3–STATE Output Leakage Current	V _{OUT} = V _{CC} or GND Enable G = V _{IH}	6.0	–	±0.5	±5.0	±10	μA
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND, I _{OUT} = 0 μA	6.0	–	8.0	80	160	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. For a power supply of $5\text{ V} \pm 10\%$ the worst case output voltages (V_{OH} , and V_{OL}) occur for HC at 4.5 V. Thus the 4.5 V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5\text{ V}$ and 4.5 V respectively. (The V_{IH} value at 5.5 V is 3.85 V.) The worst case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0 V values should be used.

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AC ELECTRICAL CHARACTERISTICS

($V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $t_r = t_f = 6\text{ ns}$)

Symbol	Parameter	Conditions	Typ.	Guaranteed Limit	Unit
t_{PHL} , t_{PLH}	Maximum Propagation Delay	$C_L = 45\text{ pF}$	12	17	ns
t_{PZL} , t_{PZH}	Maximum Output Enable Time	$R_L = 1\text{ k}\Omega$, $C_L = 45\text{ pF}$	24	35	ns
t_{PLZ} , t_{PHZ}	Maximum Output Disable Time	$R_L = 1\text{ k}\Omega$, $C_L = 5\text{ pF}$	18	25	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

($V_{CC} = 2.0\text{ V}$ to 6.0 V , $C_L = 50\text{ pF}$, $t_r = t_f = 6\text{ ns}$, unless otherwise specified)

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C		T _A = –40°C to 85°C	T _A = –55°C to 125°C	Unit			
				Typ.	Guaranteed Limits						
t _{PHL} , t _{PLH}	Maximum Propagation Delay	C _L = 50 pF	2.0	31	90	113	135	ns			
		C _L = 150 pF		41	96	116	128				
		C _L = 50 pF	4.5	13	18	23	27				
		C _L = 150 pF		17	22	28	33				
		C _L = 50 pF	6.0	11	15	19	23				
		C _L = 150 pF		14	19	23	28				
		t _{PZH} , t _{PZL}	Maximum Output Enable Time	R _L = 1 kΩ	2.0	71	190		240	285	ns
				C _L = 50 pF		81	240		300	360	
C _L = 150 pF	4.5			26	38	48	57				
C _L = 50 pF				31	48	60	72				
		C _L = 150 pF	6.0	21	32	41	48				
		C _L = 50 pF		25	41	51	61				
		t _{PHZ} , t _{PLZ}	Maximum Output Disable Time	R _L = 1 kΩ	2.0	39	135		169	203	ns
				C _L = 50 pF	4.5	20	27		34	41	
	6.0			18	23	29	34				
t _{TLH} , t _{THL}	Output Rise and Fall Time			C _L = 50 pF	2.0	20	60	75	90	ns	
			4.5	6	12	15	18				
			6.0	5	10	13	15				
		C _{PD}	Power Dissipation Capacitance (Note 3)	G̅ = V _{IL} G̅ = V _{IH}		50 5	–	–	–		pF
C _{IN}	Maximum Input Capacitance			5	10	10	10	pF			
C _{IN/OUT}	Maximum Input/Output Capacitance, A or B			15	20	20	20	pF			

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

MM74HC245A

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MM74HC245AWM	HC245A	SOIC-20 WB (Pb-Free)	38 Units / Tube
MM74HC245AWMX	HC245A	SOIC-20 (Pb-Free)	1000 / Tape & Reel
MM74HC245AMTC	HC 245A	TSSOP-20 WB (Pb-Free)	75 Units / Tube
MM74HC245AMTCX	HC 245A	TSSOP-20 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

SOIC-20, 300 mils
CASE 751BJ
ISSUE O

DATE 19 DEC 2008



TOP VIEW

SYMBOL	MIN	NOM	MAX
A	2.36	2.49	2.64
A1	0.10		0.30
A2	2.05		2.55
b	0.31	0.41	0.51
c	0.20	0.27	0.33
D	12.60	12.80	13.00
E	10.01	10.30	10.64
E1	7.40	7.50	7.60
e	1.27 BSC		
h	0.25		0.75
L	0.40	0.81	1.27
θ	0°		8°
$\theta 1$	5°		15°



SIDE VIEW



END VIEW

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-013.

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SCALE 1:1

SOIC-20 WB
CASE 751D-05
ISSUE H

DATE 22 APR 2015



NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
b	0.35	0.49
c	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

GENERIC
MARKING DIAGRAM*



XXXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week
G = Pb-Free Package

RECOMMENDED
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

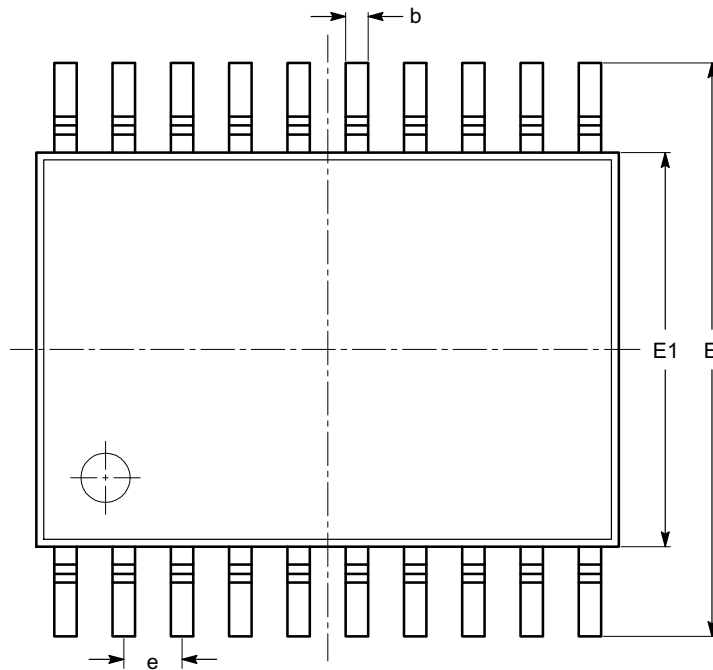
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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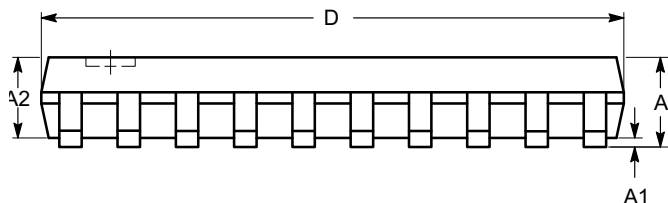
TSSOP20, 4.4x6.5
CASE 948AQ
ISSUE A

DATE 19 MAR 2009

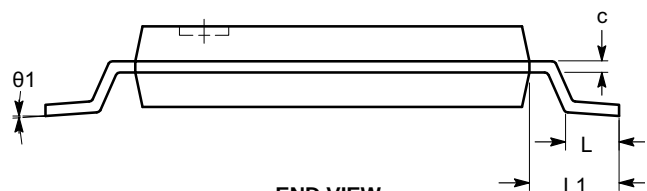


TOP VIEW

SYMBOL	MIN	NOM	MAX
A			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
c	0.09		0.20
D	6.40	6.50	6.60
E	6.30	6.40	6.50
E1	4.30	4.40	4.50
e	0.65 BSC		
L	0.45	0.60	0.75
L1	1.00 REF		
θ	0°		8°



SIDE VIEW



END VIEW

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

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